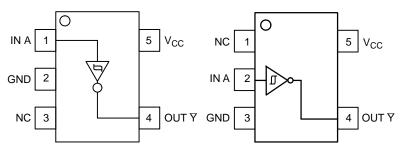
Schmitt Inverter

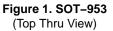
The NL17SG14 MiniGate[™] is an advanced high–speed CMOS Schmitt Inverter in ultra–small footprint.

The NL17SG14 input structure provides protection when voltages up to 4.6 V are applied.

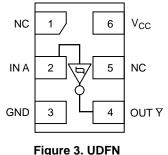
Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: $t_{PD} = 3.7$ ns (Typ) at $V_{CC} = 3.0$ V, $C_L = 15$ pF
- Low Power Dissipation: $I_{CC} = 0.5 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant









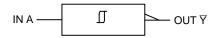


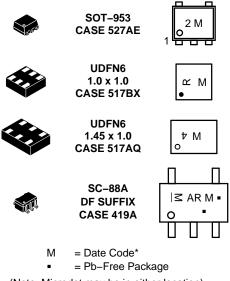
Figure 4. Logic Symbol



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MARKING DIAGRAMS



(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

| | PIN A | SSIGNMENT | Г |
|---|-----------------|-----------------|-----------------|
| | SOT-953 | SC-88A | UDFN6 |
| 1 | IN A | NC | NC |
| 2 | GND | IN A | IN A |
| 3 | NC | GND | GND |
| 4 | Ουτ γ | OUT Y | OUT 7 |
| 5 | V _{CC} | V _{CC} | NC |
| 6 | | | V _{CC} |

FUNCTION TABLE

| A Input | Y Output |
|---------|----------|
| L | Н |
| Н | L |

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MAXIMUM RATINGS

| Symbol | Paramete | er | Value | Unit |
|------------------|---|---|---|------|
| V _{CC} | DC Supply Voltage | | –0.5 to +5.5 | V |
| V _{IN} | DC Input Voltage | | -0.5 to +4.6 | V |
| V _{OUT} | DC Output Voltage | Output at High or Low State Power–Down Mode ($V_{CC} = 0 V$) | -0.5 to V _{CC} + 0.5 -0.5 to +4.6 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < GND | -20 | mA |
| Ι _{ΟΚ} | DC Output Diode Current | V _{OUT} < GND | -20 | mA |
| I _{OUT} | DC Output Source/Sink Current | | ±20 | mA |
| I _{CC} | DC Supply Current per Supply Pin | | ±20 | mA |
| I _{GND} | DC Ground Current per Ground Pin | | ±20 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| ΤL | Lead Temperature, 1 mm from Case for 10 Sec | conds | 260 | °C |
| TJ | Junction Temperature Under Bias | | +150 | °C |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V–0 @ 0.125 in | |
| V_{ESD} | ESD Withstand Voltage | Human Body Model (Note 2) Machine Model (Note 3) | >2000 >100 | V |
| ILATCHUP | Latchup Performance Above | V_{CC} and Below GND at 125°C (Note 4) | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality Should not be assumed, damage may occur and reliability may be affected.
 Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
 Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.

4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Characteristics | Min | Max | Unit |
|-----------------------|---|------------|------------------------|------|
| V _{CC} | Positive DC Supply Voltage | 0.9 | 3.6 | V |
| V _{IN} | Digital Input Voltage | 0.0 | 3.6 | V |
| V _{OUT} | Output Voltage Output at High or Low State Power–Down Mode (V _{CC} = 0 V) | 0.0 0.0 | V _{CC} 3.6 | V |
| T _A | Operating Temperature Range | -55 | +125 | °C |
| $\Delta t / \Delta V$ | Input Transition Rise or Fail Rate | 0 | No Limit | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

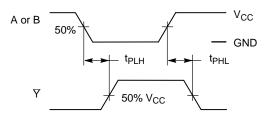
| | | | | V _{cc} | | T _A = 25°C | | –55°C ≤ T _A ≤ 125°C | | |
|-----------------|-----------------------------|--|----------------------------|-----------------|---------------------------|-----------------------|---------------------------|--------------------------------|---------------------------|------|
| Symbol | Parameter | c | Condition | (V) | Min | Тур | Max | Min | Max | Unit |
| V_{T+} | Positive-Going | | | 0.9 | 0.64 | 0.7 | 0.86 | 0.62 | 0.87 | |
| | Input Threshold Voltage | | | 1.1 | 0.73 | 0.81 | 0.95 | 0.71 | 1 | |
| | | | | 1.4 | 0.86 | 0.94 | 1.16 | 0.84 | 1.2 | |
| | | | | 1.65 | 0.95 | 1.06 | 1.25 | 0.94 | 1.3 | V |
| | | | | 2.3 | 1.22 | 1.36 | 1.6 | 1.18 | 1.65 | |
| | | | | 3.0 | 1.51 | 1.8 | 2.05 | 1.38 | 2.1 | |
| V _{T-} | Negative- | | | 0.9 | 0.09 | 0.23 | 0.30 | 0.08 | 0.33 | |
| | Going Input Threshold | | | 1.1 | 0.15 | 0.33 | 0.39 | 0.12 | 0.43 | |
| | Voltage | | | 1.4 | 0.3 | 0.47 | 0.54 | 0.25 | 0.55 | |
| | | | | 1.65 | 0.35 | 0.6 | 0.65 | 0.3 | 0.65 | V |
| | | | | 2.3 | 0.55 | 0.85 | 0.88 | 0.5 | 0.88 | |
| | | | | 3.0 | 0.95 | 1.13 | 1.16 | 0.9 | 1.16 | |
| V _H | Hysteresis | | | 0.9 | 0.15 | 0.5 | 0.75 | 0.2 | 0.8 | |
| | Voltage | | | 1.1 | 0.15 | 0.5 | 0.75 | 0.2 | 0.8 | |
| | | | | 1.4 | 0.15 | 0.5 | 0.75 | 0.2 | 0.8 | |
| | | | | 1.65 | 0.15 | 0.5 | 0.75 | 0.2 | 0.8 | V |
| | | | | 2.3 | 0.15 | 0.5 | 0.75 | 0.2 | 0.8 | |
| | | | | 3.0 | 0.25 | 0.65 | 0.85 | 0.3 | 0.9 | |
| V _{OH} | High–Level | V _{IN} = | I _{OH} = -20 μA | 0.9 | 0.75 | | | 0.75 | | V |
| | Output Voltage | V _{IH} or V _{IL} | I _{OH} = -0.3 mA | 1.1 to 1.3 | 0.75 x V _{CC} | | | 0.75 x V _{CC} | | |
| | | | I _{OH} = -1.7 mA | 1.4 to 1.6 | 0.75 x V _{CC} | | | 0.75 x V _{CC} | | |
| | | | I _{OH} = -3.0 mA | 1.65 to 1.95 | V _{CC} – 0.45 | | | V _{CC} – 0.45 | | |
| | | | $I_{OH} = -4.0 \text{ mA}$ | 2.3 to 2.7 | 2.0 | | | 2.0 | | |
| | | | I _{OH} = -8.0 mA | 3.0 to 3.6 | 2.48 | | | 2.48 | | |
| V _{OL} | Low–Level Output Voltage | V _{IN} = V _{IH} or | I _{OL} = 20 μA | 0.9 | | | 0.1 | | 0.1 | V |
| | Output voltage | VIL | I _{OL} = 0.3 mA | 1.1 to 1.3 | | | 0.25 x V _{CC} | | 0.25 x V _{CC} | |
| | | | I _{OL} = 1.7 mA | 1.4 to 1.6 | | | 0.25xV cc | | 0.25 x V _{CC} | |
| | | | I _{OL} = 3.0 mA | 1.65 to 1.95 | | | 0.45 | | 0.45 | |
| | | | l _{OL} = 4.0 mA | 2.3 to 2.7 | | | 0.4 | | 0.4 | |
| | | | l _{OL} = 8.0 mA | 3.0 to 3.6 | | | 0.4 | | 0.4 | |
| I _{IN} | Input Leakage Current | 0 ≤ | $V_{IN} \leq 3.6 V$ | 0 to 3.6 | | | ±0.1 | | ±1.0 | μΑ |
| I _{CC} | Quiescent Supply Current | V _{IN} = | V _{CC} or GND | 3.6 | | | 0.5 | | 10.0 | μA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

| | | | | | T _A = 25 °C | ; | | _ = ⊳ +125°C | |
|--------------------|---|---|---------------------|-----|------------------------|------|-----|-----------------|------|
| Symbol | Parameter | Test Condition | V _{CC} (V) | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , | Propagation Delay, A or Y | $C_L = 10 \text{ pF},$ | 0.9 | - | 27.3 | - | - | - | ns |
| t _{PHL} | AOIY | $R_L = 1 M\Omega$ | 1.1 to 1.3 | - | 13.0 | 22.6 | 1.0 | 35.9 | |
| | | | 1.4 to 1.6 | - | 7.5 | 10.5 | 1.0 | 11.3 | |
| | | | 1.65 to 1.95 | - | 6.0 | 7.8 | 1.0 | 8.2 | |
| | | | 2.3 to 2.7 | - | 4.3 | 5.4 | 1.0 | 5.8 | |
| | | | 3.0 to 3.6 | - | 3.5 | 4.4 | 1.0 | 4.6 | |
| | | $C_{L} = 15 pF,$ | 0.9 | - | 29.5 | - | - | - | ns |
| | | $R_L = 1 M\Omega$ | 1.1 to 1.3 | - | 14.3 | 25.1 | 1.0 | 41.6 | |
| | | | 1.4 to 1.6 | - | 8.0 | 11.5 | 1.0 | 12.6 | |
| | | | 1.65 to 1.95 | - | 6.3 | 8.4 | 1.0 | 8.7 | |
| | | | 2.3 to 2.7 | - | 4.6 | 5.7 | 1.0 | 6.1 | |
| | | | 3.0 to 3.6 | - | 3.7 | 4.6 | 1.0 | 5.0 | |
| | | $C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$ | 0.9 | - | 40.5 | - | - | - | ns |
| | | $R_{L} = 1 \text{ IVIS2}$ | 1.1 to 1.3 | - | 19.6 | 35.7 | 1.0 | 58.1 | |
| | | | 1.4 to 1.6 | - | 10.7 | 15.8 | 1.0 | 17.6 | |
| | | | 1.65 to 1.95 | - | 7.8 | 10.7 | 1.0 | 11.7 | |
| | | | 2.3 to 2.7 | - | 5.4 | 6.9 | 1.0 | 8.1 | |
| | | | 3.0 to 3.6 | - | 4.3 | 5.2 | 1.0 | 6.1 | |
| C _{IN} | Input Capacitance | | 0 to 3.6 | | 3 | - | _ | _ | pF |
| C _O | Output Capacitance | V _O = GND | 0 | | 3 | _ | _ | _ | pF |
| C _{PD} | Power Dissipation Capacitance (Note 5) | f = 10 MHz | 0.9 to 3.6 | - | 4 | - | _ | _ | pF |

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3.0 ns)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.





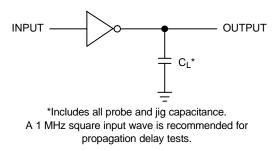


Figure 6. Test Circuit

ORDERING INFORMATION

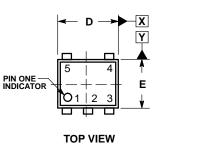
| Device | Package | Shipping [†] |
|------------------------------------|------------------------------|-----------------------|
| NL17SG14P5T5G | SOT–953 (Pb–Free) | 8000 / Tape & Reel |
| NL17SG14DFT2G | SC–88A (Pb–Free) | 3000 / Tape & Reel |
| NLV17SG14DFT2G* | SC–88A (Pb–Free) | 3000 / Tape & Reel |
| NL17SG14AMUTCG (In Development) | UDFN6 1.45x1 mm (Pb-Free) | 3000 / Tape & Reel |
| NL17SG14CMUTCG (In Development) | UDFN6 1x1 mm (Pb-Free) | 3000 / Tape & Reel |

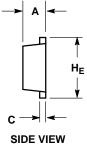
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

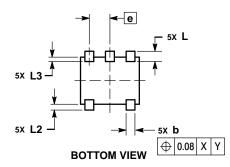
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

SOT-953 CASE 527AE ISSUE E



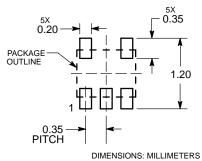




NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| FLASH, PROTRUSIONS, OR G | | | | | | | |
|--------------------------|-------------|---------|------|--|--|--|--|
| | MILLIMETERS | | | | | | |
| DIM | MIN | NOM | MAX | | | | |
| Α | 0.34 | 0.37 | 0.40 | | | | |
| b | 0.10 | 0.15 | 0.20 | | | | |
| С | 0.07 | 0.12 | 0.17 | | | | |
| D | 0.95 | 1.00 | 1.05 | | | | |
| E | 0.75 | 0.80 | 0.85 | | | | |
| е | | 0.35 BS | С | | | | |
| HE | 0.95 | 1.00 | 1.05 | | | | |
| L | 0.175 REF | | | | | | |
| L2 | 0.05 | 0.10 | 0.15 | | | | |
| L3 | | | 0.15 | | | | |

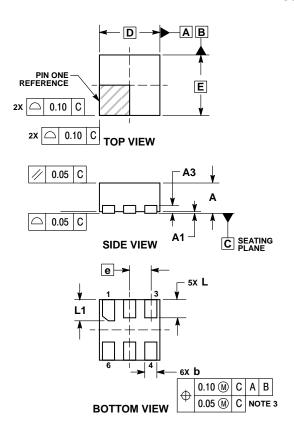
SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

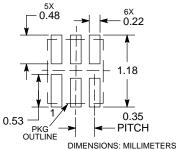
UDFN6 1.0x1.0, 0.35P CASE 517BX ISSUE O



- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| BURRS AND MOLD FL | | | | | | | |
|-------------------|----------|-------------|--|--|--|--|--|
| | MILLIN | MILLIMETERS | | | | | |
| DIM | MIN | MAX | | | | | |
| Α | 0.45 | 0.55 | | | | | |
| A1 | 0.00 | 0.05 | | | | | |
| A3 | 0.13 REF | | | | | | |
| b | 0.12 | 0.22 | | | | | |
| D | 1.00 | BSC | | | | | |
| Е | 1.00 | BSC | | | | | |
| е | 0.35 BSC | | | | | | |
| L | 0.25 | 0.35 | | | | | |
| L1 | 0.30 | 0.40 | | | | | |

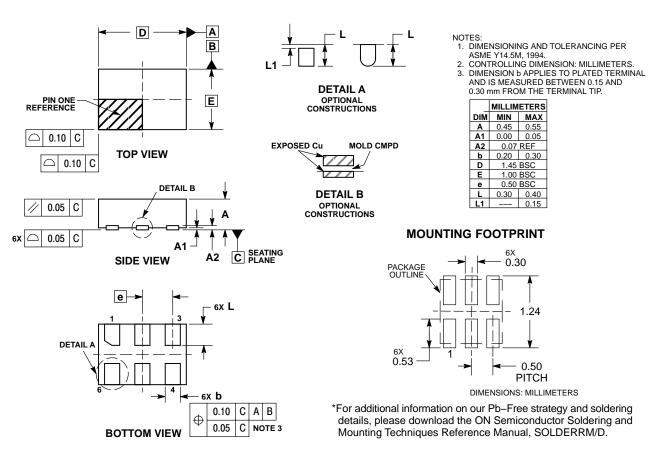
RECOMMENDED **SOLDERING FOOTPRINT***



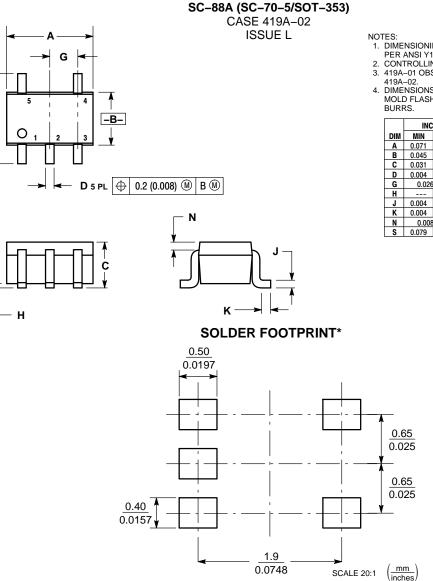
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

UDFN6 1.45x1.0, 0.5P CASE 517AQ ISSUE O



PACKAGE DIMENSIONS



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DIMENSIONING AND TOLERANCING

PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

419A–01 OBSOLETE. NEW STANDARD 419A–02.

4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE

| | INCHES | | MILLIMETERS | | |
|-----|-----------|-------|-------------|------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.071 | 0.087 | 1.80 | 2.20 | |
| В | 0.045 | 0.053 | 1.15 | 1.35 | |
| С | 0.031 | 0.043 | 0.80 | 1.10 | |
| D | 0.004 | 0.012 | 0.10 | 0.30 | |
| G | 0.026 | BSC | 0.65 BSC | | |
| Η | | 0.004 | | 0.10 | |
| L | 0.004 | 0.010 | 0.10 | 0.25 | |
| Κ | 0.004 | 0.012 | 0.10 | 0.30 | |
| Ν | 0.008 REF | | 0.20 | REF | |
| s | 0.079 | 0.087 | 2.00 | 2.20 | |

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